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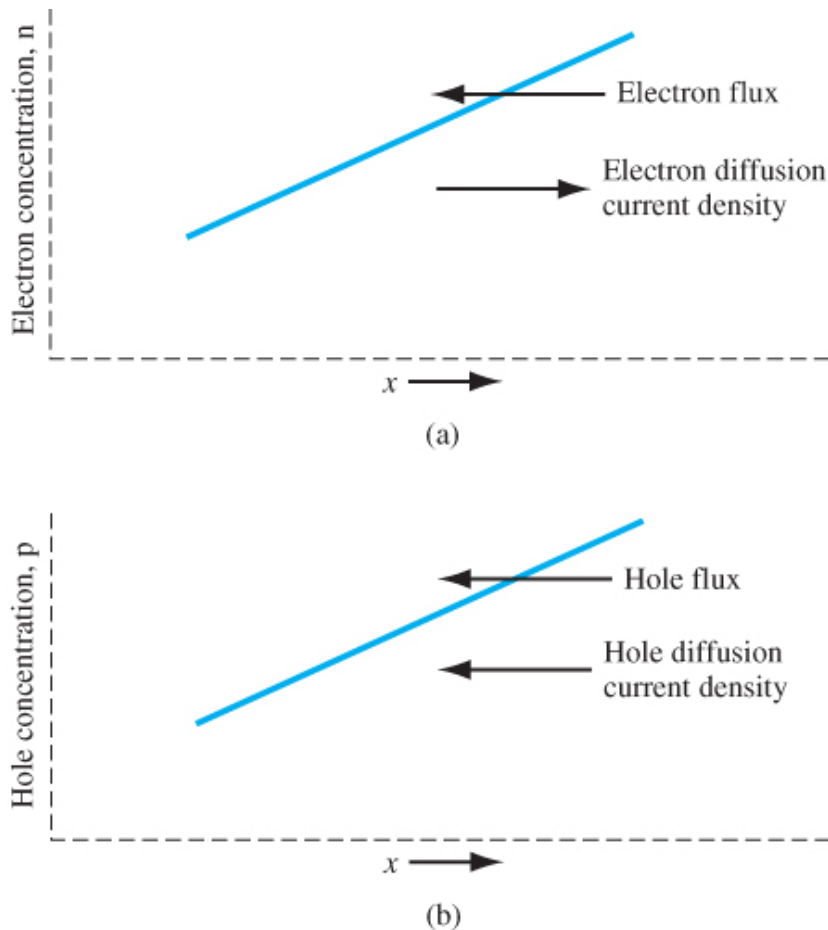


Figure 5.11 | (a) Diffusion of electrons due to a density gradient. (b) Diffusion of holes due to a density gradient.

- Note that current density is defined as the flow of **positive** charges per unit area.
- Therefore, in part (a), the electron diffusion current density (left to right) goes in the opposite direction to the flux of electrons from higher to lower concentration n (right to left).
- Whereas, in part (b), the hole diffusion current density (right to left) goes in the same direction as the flux of holes from higher to lower concentration p (also right to left).
- This explains the sign difference between the 1D diffusion current density equations-

$$J_{nx|dif} = eD_n \frac{dn}{dx} \quad (5.33) \quad \text{and} \quad J_{px|dif} = -eD_p \frac{dp}{dx} \quad (5.34).$$